LITE-ON SEMICONDUCTOR

RS3A thru RS3M

SURFACE MOUNT
FAST RECOVERY RECTIFIERS

REVERSE VOLTAGE - **50** to **1000** Volts
FORWARD CURRENT - **3.0** Amperes

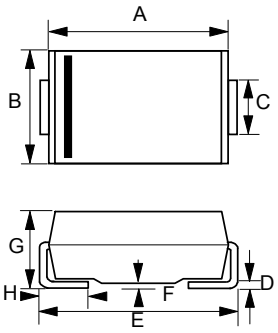
FEATURES

- Fast switching for high efficiency
- For surface mounted applications
- Glass passivated chip
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Case : Molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.007 ounces, 0.21 grams

SMC



SMC		
DIM.	MIN.	MAX.
A	6.60	7.11
B	5.59	6.22
C	2.92	3.18
D	0.15	0.31
E	7.75	8.13
F	0.05	0.20
G	2.01	2.62
H	0.76	1.52
All Dimensions in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T_L =75°C	$I_{(AV)}$	3.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	I_{FSM}	100							A
Maximum forward Voltage at 3.0A DC	V_F	1.3							V
Maximum DC Reverse Current @T_J =25°C at Rated DC Blocking Voltage @T_J =125°C	I_R	5 250							uA
I^2t Rating for fusing (3ms < t < 8.3ms)	I^2t	41							A^2S
Maximum Reverse Recovery Time (Note 1)	T_{RR}	150				250	500		ns
Typical JunctionCapacitance (Note 2)	C_J	50							pF
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$	10							°C/W
Typical Thermal Resistance (Note 4)	$R_{\theta JA}$	50							°C/W
Operating Temperature Range	T_J	-55 to +150							℃
Storage Temperature Range	T_{STG}	-55 to +150							℃

NOTES :1. Reverse Recovery Test Conditions :I_F=0.5A,I_R=1.0A,I_{RR}=0.25A.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3. Thermal Resistance Junction to Lead.
4. Thermal Resistance Junction to Ambient.

REV. 3, Jan-2010, KSEC01

RATING AND CHARACTERISTIC CURVES
RS3A thru RS3M

FIG.1 - FORWARD CURRENT DERATING CURVE

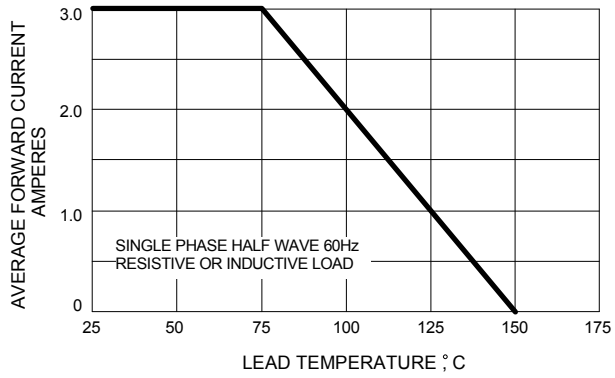


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

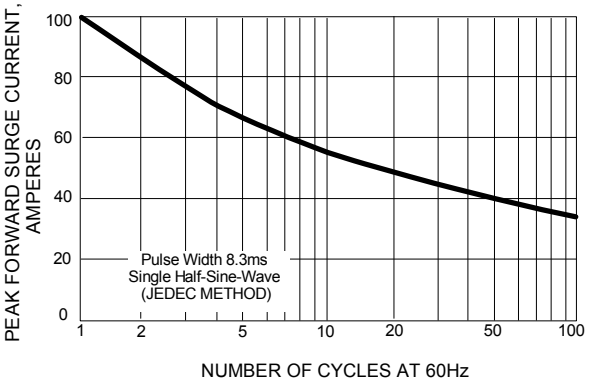


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

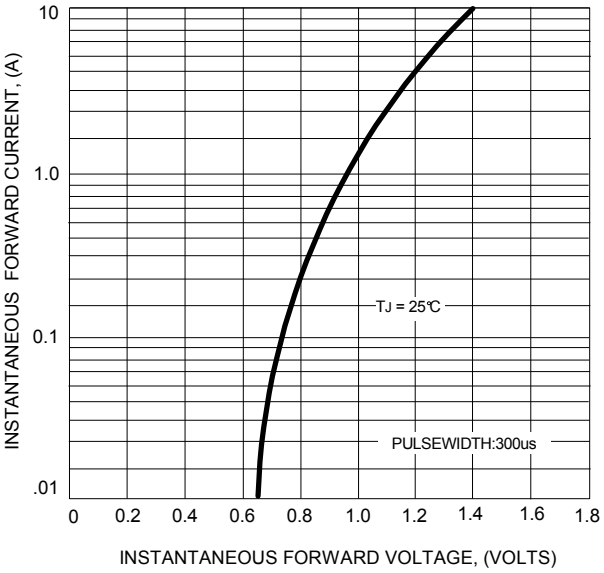


FIG.4 - TYPICAL REVERSE CHARACTERISTICS